



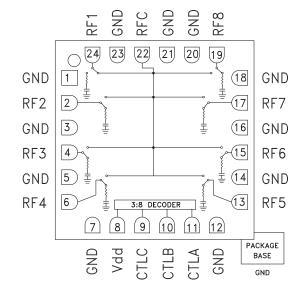
ARTH FRIENDLY

Typical Applications

The HMC253LC4 is ideal for:

- Basestations & Repeaters
- WiMAX/WiBro & Fixed Wireless
- Cellular/3G Infrastructure
- CATV/DBS
- Military & Hi-Rel

Functional Diagram



GaAs MMIC SP8T NON-REFLECTIVE SWITCH, DC - 3.5 GHz

Features

Ceramic, RoHS Compliant 4x4mm SMT Package Non-Reflective Topology Low Insertion Loss: 1.2 dB Single Positive Supply: Vdd = +5V Integrated 3:8 TTL/CMOS Decoder: 0/+3V

General Description

The HMC253LC4 is a non-reflective SP8T switch in a leadless RoHS compliant 4x4 mm ceramic SMT package featuring wideband operation from DC to 3.5 GHz. The switch offers a single positive bias and true TTL/CMOS compatibility enabling it to operate with 0/+3V control and a +5V supply. A 3:8 decoder is integrated on the switch requiring only 3 control lines and a positive bias to select each path. The HMC253LC4 SP8T will replace multiple configurations of SP4T and SPDT MMIC switches.

Electrical Specifications, $T_4 = +25^\circ$ C, For TTL Control and Vdd = +5V in a 50 Ohm system

Parameter		Frequency	Min.	Тур.	Max.	Units
Insertion Loss		DC - 2.0 GHz DC - 3.0 GHz DC - 3.5 GHz		1.1 1.2 1.3	1.5 1.6 1.7	dB dB dB
Isolation		DC - 2.0 GHz DC - 3.0 GHz DC - 3.5 GHz	35 31 30	40 36 35		dB dB dB
Return Loss	"On State"	0.3 - 3.0 GHz 0.3 - 3.5 GHz	15 12	18 14		dB dB
Return Loss (RF1-8)	"Off State"	0.3 - 3.5 GHz 0.5 - 3.5 GHz	7 10	10 14		dB dB
Input Power for 1 dB Compression		0.5 - 3.5 GHz	20	24		dBm
Input Third Order Intercept (Two-Tone Input Power = +7 dBm Each Tone)		0.5 - 3.5 GHz	40	43		dBm
Switching Characteristics		0.3 - 3.5 GHz				
tRISE, tFALL (10/90% RF) tON, tOFF (50% CTL to 10/90% RF)				30 100		ns ns

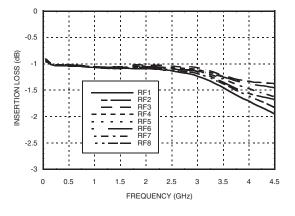
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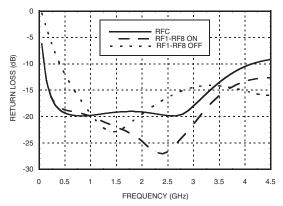


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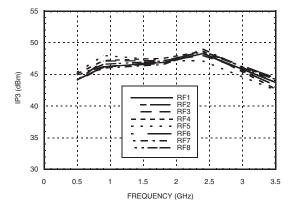
Insertion Loss



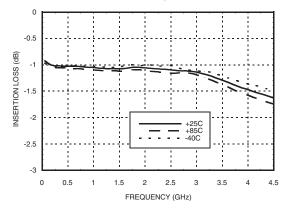
Return Loss



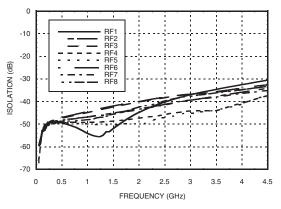
Input IP3



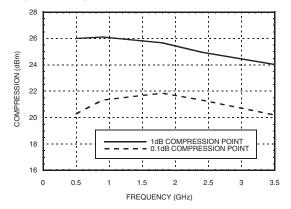
Insertion Loss vs. Temperature

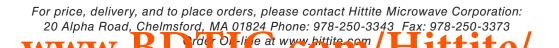


Isolation



Input Compression







Signal Path State

ROHSV EARTH FRIENDLY

GaAs MMIC SP8T NON-REFLECTIVE SWITCH, DC - 3.5 GHz

Bias Voltage & Current

Vdd Range = +5.0 Vdc ± 10%			
Vdd (Vdc) Idd (Typ.) (mA)		Idd (Max.) (mA)	
+5.0	6.0	9.0	

TTL/CMOS Control Voltages

State	Bias Condition
Low	0 to +0.8 Vdc @ 5 uA Typ.
High	+2.0 to +5.0 Vdc @ 70 uA Typ.

Control Input

Truth Table

Control input		Signal Path State	
А	В	С	RFCOM to:
Low	Low	Low	RF1
High	Low	Low	RF2
Low	High	Low	RF3
High	High	Low	RF4
Low	Low	High	RF5
High	Low	High	RF6
Low	High	High	RF7
High	High	High	RF8

NOTE:

DC Blocking capacitors are required at ports RFC and RF1, 2, 3, 4, 5, 6, 7, 8.

Absolute Maximum Ratings

Bias Voltage Range (Port Vdd)	+7.0 Vdc
Control Voltage Range (A, B, C)	-0.5V to Vdd +1Vdc
Channel Temperature	150 °C
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
Maximum Input Power Vdd = +5V	+20 dBm (0.05 - 0.5 GHz) +25 dBm (0.5 - 3.5 GHz)

BOTTOM VIEW

ELECTROSTATIC SENSITIVE DEVICE OBSERVE HANDLING PRECAUTIONS

Outline Drawing

PIN 24 0.157±0.005 .014 .009 0.36 .013 [0.32] REF [4.00±0.13] 24 19 PIN 1 PIN 1 18 D 0.157±0.005 [4.00±0.13] D H253 D 0.56 .022 .017 XXX \square 101 D 0. 13 6 $\Phi \Box \Box \Box \Box \Box$ 12 7 .098 [2.50] LOT NUMBER SQUARE EXPOSED 0.040 [1.02] GROUND 122 [3.10] MAX PADDLE SEATING PLANE NOTES: 1. PACKAGE BODY MATERIAL: ALUMINA -C-2. LEAD AND GROUND PADDLE PLATING: 30-80 MICROINCHES GOLD OVER 50 MICROINCHES MINIMUM NICKEL 3. DIMENSIONS ARE IN INCHES [MILLIMETERS]. 4. LEAD SPACING TOLERANCE IS NON-CUMULATIVE. 5. PACKAGE WARP SHALL NOT EXCEED 0.05mm DATUM -C-6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.

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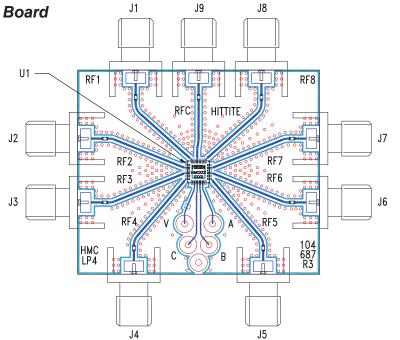


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Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1, 3, 5, 7, 12, 14, 16, 18, 20, 21, 23	GND	Package bottom has exposed metal paddle that must also be connected to RF ground.	
2, 4, 6, 13, 15, 17, 19, 22, 24	RF1 - RF8 & RFC	This pin is DC coupled and matched to 50 Ohms. Blocking capacitors are required.	
8	Vdd	Supply Voltage +5.0 Vdc ±10%	VddO
9	CTLC		O Vdd
10	CTLB	See truth table and control voltage table.	
11	CTLA		

Evaluation Circuit Board



List of Materials for Evaluation PCB 107780^[1]

Item	Description
J1 - J9	PCB Mount SMA Connector
J10 - J14	DC Pin
C1 - C9	100 pF Capacitor, 0402 Pkg.
C10	0.01 uF Capacitor, 0603 Pkg.
U1	HMC253LC4 SP8T Switch
PCB [2]	104687 Eval Board

Reference this number when ordering complete evaluation PCB
Circuit Board Material: Rogers 4350

The circuit board used in the final application should be generated with proper RF circuit design techniques. Signal lines at the RF ports should have 50 ohm impedance while the package ground leads should be connected directly to the ground plane similar to that shown above. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown above is available from Hittite Microwave Corporation upon request.

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